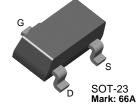


MMBF5103

N-Channel Switch

- This device is designed for low level analog switching, sample and hold circuits and chopper stabilized amplifiers.
- Sourced from Process 51.
- See J111 for characteristics.



1. Drain 2. Source 3. Gate

Absolute Maximum Ratings* T_a=25°C unless otherwise noted

| Symbol | Parameter | Value | Units |
|-----------------------------------|--|------------|-------|
| V_{DG} | Drain-Gate Voltage | 40 | V |
| V _{GS} | Gate-Source Voltage | -40 | V |
| I _{GF} | Forward Gate Current | 50 | mA |
| T _J , T _{STG} | Operating and Storage Junction Temperature Range | - 55 ~ 150 | °C |

^{*} These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

- These ratings are based on a maximum junction temperature of 150 degrees C.
 These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations

Electrical Characteristics T_a=25°C unless otherwise noted

| Symbol | Parameter | Test Condition | Min. | Max. | Units |
|----------------------|-----------------------------------|--|------|--------------|----------|
| Off Charact | eristics | • | | • | • |
| V _{(BR)GSS} | Gate-Source Breakdown Voltage | $I_G = 1.0 \mu A, V_{DS} = 0$ | -40 | | V |
| I _{GSS} | Gate Reverse Current | $V_{GS} = -15V, V_{DS} = 0$ $V_{GS} = -15V, V_{DS} = 0, T_a = 125^{\circ}C$ | | -200 -500 | pA nA |
| V _{GS(off)} | Gate-Source Cutoff Voltage | $V_{DS} = 20V, I_{D} = 1.0nA$ | -1.2 | -2.7 | V |
| V _{GS(f)} | Gate-Source Forward Voltage | $I_G = 1.0 \text{mA}, V_{DS} = 0$ | | 1.0 | V |
| On Characte | eristics | · | | | |
| I _{DSS} | Zero-Gate Voltage Drain Current * | V _{DS} = 15V, V _{GS} = 0 | 10 | 40 | mA |
| Small Signa | I Characteristics | · | | • | • |
| C _{ISS} | Input Capacitance | $V_{DS} = 15V, V_{GS} = 0, f = 1.0MHz$ 16 | | 16 | pF |
| C _{rss} | Reverse Transfer Capacitance | V _{GS} = -15V, f = 1.0MHz | | 6.0 | pF |

Pulse Test: Pulse Width $\leq 300 \mu s, \ Duty \ Cycle \leq 1.0\%$

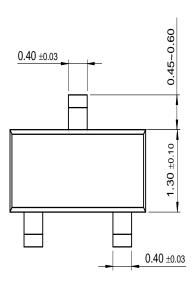
Thermal Characteristics T_a=25°C unless otherwise noted

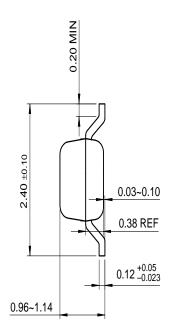
| Symbol | Parameter | Max. | Units |
|-----------------|---|------|-------|
| P _D | Total Device Dissipation | 350 | mW |
| | Derate above 25°C | 2.8 | mW/°C |
| $R_{\theta JA}$ | Thermal Resistance, Junction to Ambient | 556 | °C/W |

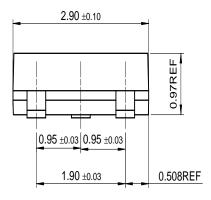
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Package Dimensions

SOT-23







Dimensions in Millimeters

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PRODUCT STATUS DEFINITIONS

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|--------------------------|---------------------------|---|
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